

NPN Silicon Transistor

Collector

3

 $(T_{a}=25^{\circ}C)$

Descriptions

- General purpose amplifier
- High voltage application

Features

- high collector breakdown voltage : $V_{CBO} = 180V$, $V_{CEO} = 160V$
- Low collector saturation voltage : $V_{CE(sat)} = 0.5V(MAX.)$
- Complementary pair with SBT5401F

Ordering Information

1

3 Base Emitter 2 2 SOT-23F

PIN Connection

<u>FNF</u> <u> </u> 1 2	SOT-23F
	1 2

1 Device Code 2 Year&Week Code

Absolute maximum ratings

mostrate maximum ratings			(1a-25 C)
Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V _{CBO}	180	V
Collector-Emitter voltage	V _{CEO}	160	V
Emitter-Base voltage	V _{EBO}	6	V
Collector current	Ι _C	600	mA
Collector dissipation	Pc	200	mW
Junction temperature	Tj	150	٥C
Storage temperature	T _{stg}	-55~150	٥C

Electrical Characteristics

Electrical Characteristics (Ta=25°						
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV_{CBO}	$I_{C} = 100 \mu A$, $I_{E} = 0$	180	-	-	V
Collector-Emitter breakdown voltage	BV_{CEO}	$I_{C}=1mA$, $I_{B}=0$	160	-	-	V
Emitter-Base breakdown voltage	BV _{EBO}	$I_{E} = 10 \mu A$, $I_{C} = 0$	6	-	-	V
Collector cut-off current	I _{CBO}	$V_{CB} = 120V, I_{E} = 0$	-	-	100	nA
Emitter cut-off current	I _{EBO}	$V_{EB}=4V$, $I_{C}=0$	-	-	100	nA
DC current gain	h _{FE (1)}	V_{CE} =5V, I_{C} =1mA	80	-		-
DC current gain	h _{FE (2)}	V_{CE} =5V, I_{C} =10mA	80	-	250	-
DC current gain	h _{FE (3)}	V_{CE} =5V, I_{C} =50mA	30	-		-
Collector-Emitter saturation voltage	V _{CE(sat)(1)} *	$I_{C}=10mA$, $I_{B}=1mA$	-	-	0.2	V
Collector-Emitter saturation voltage	V _{CE(sat)(2)} *	I_{C} =50mA, I_{B} =5mA	-	-	0.5	V
Base-Emitter saturation voltage	V _{BE(sat)(1)} *	$I_{C}=10mA$, $I_{B}=1mA$	-	-	1	V
Base-Emitter saturation voltage	V _{BE(sat)(2)*}	I_{C} =50mA, I_{B} =5mA	-	-	1	V
Transition frequency	f _T	V_{CE} =10V, I_{C} =10mA	100	-	400	MHz
Collector output capacitance	C _{ob}	V_{CB} =10V, I_{E} =0, f=1MHz	-	-	6	pF

* : Pulse Tester : Pulse Width \leq 300µs, Duty Cycle \leq 2.0%

Electrical Characteristic Curves

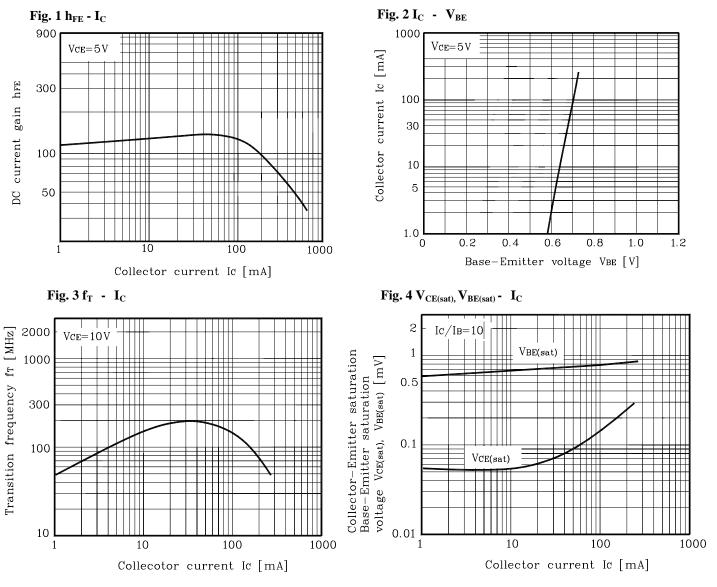
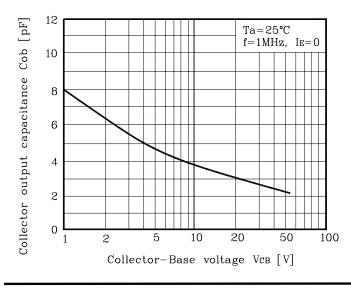
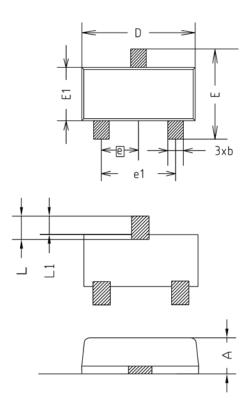
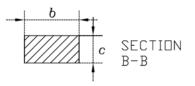


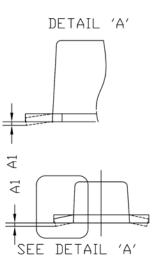
Fig. 5 $C_{ob}\,$ - $\,V_{CB}$



Outline Dimension

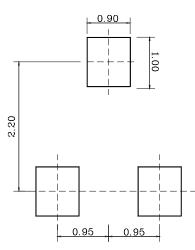






SYMBOL	N	NOTE		
STRUC	MINIMUM	NOMINAL	MAXIMUM	NUIE
A	0.80	0.90	1.00	
A1	0.00	-	0.10	
b	0.35	0.40	0.45	
С	0.10	0.15	0.20	
D	2.80	2.90	3.00	
E	2.30	2.40	2.50	
E1	1.50	1.60	1.70	
e	0.95BSC			
e1	1.80	1.90	2.00	
L	0.48	0.58	0.68	
L1	0.30	-	0.50	

*Recommend PCB solder land [Unit: mm]



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